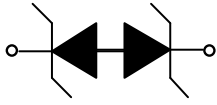


1-Line, Bi-directional, Transient Voltage Suppressor



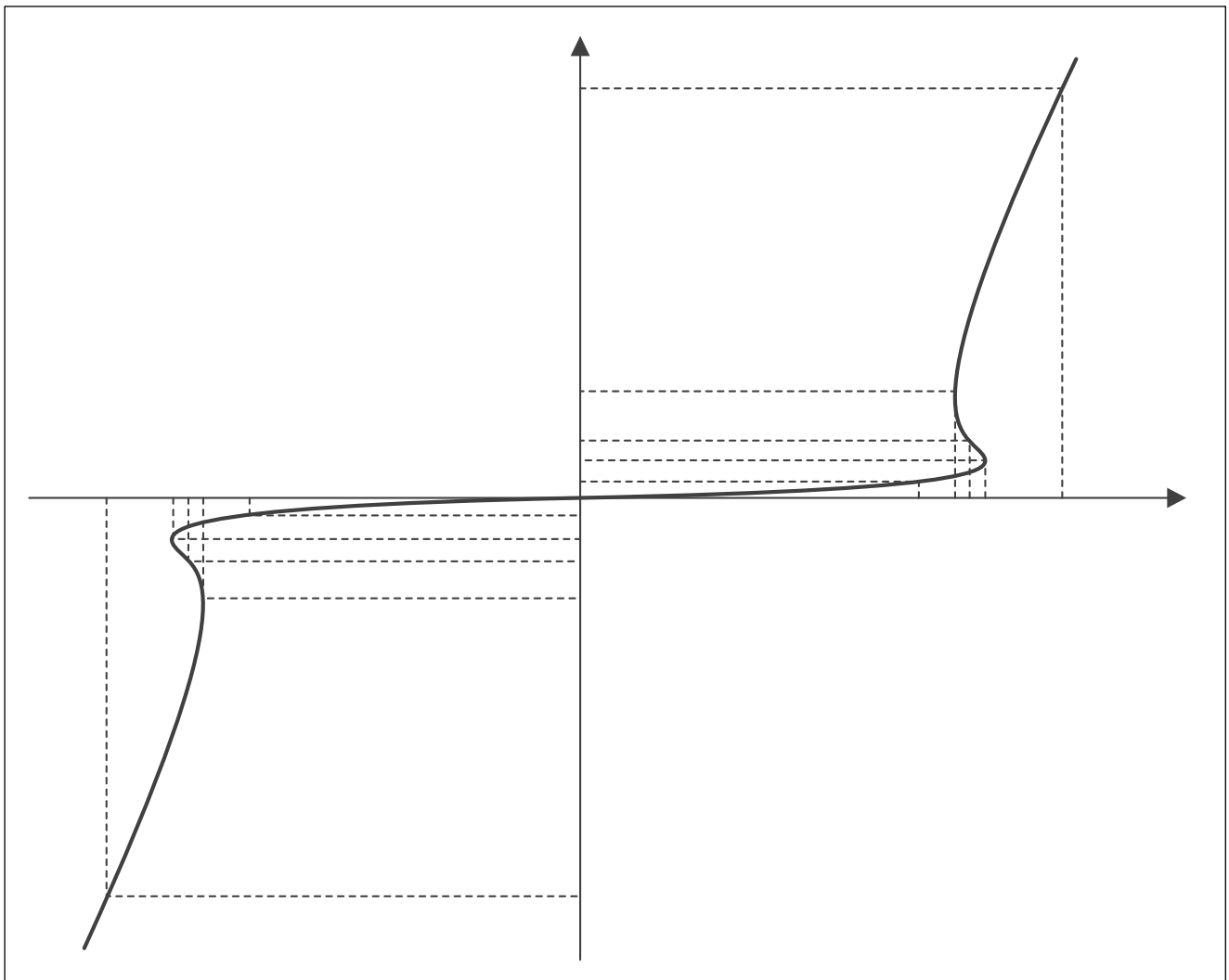
Features

- " Stand-off voltage: $\pm 7\text{V}$ Max
- " Transient protection for each line according to IEC61000-4-2(ESD): $\pm 30\text{kV}$ (contact)
- IEC61000-4-4 (EFT): 40A (5/50ns)
- IEC61000-4-5(surge): 6A (8/20 s)
- " Ultra-low capacitance: $C_J = 10\text{pF}$ typ
- " Low leakage current
- " Low clamping voltage: $V_{CL} = 12.0\text{V}$ typ. @ $I_{PP} = 16\text{A}$ (TLP)
- " Solid-state silicon technology

Mechanical Data

- " Package : DFN1006-2L
- " Terminals : Tin plated leads, solderable per J-STD-002 and JESD22-B102
- " Polarity: No marking on bi-directional types
- " Marking: 7A

Definitions of electrical characteristics



ESD7V0LB

Maximum Ratings

PARAMETER	SYMBOL	Rating	UNIT
Peak pulse power ($t_p = 8/20 \text{ s}$)	P_{pk}	84	W
Peak pulse current ($t_p = 8/20 \text{ s}$)	I_{PP}	6	A
ESD according to IEC61000-4-2 air discharge	V_{ESD}	± 30	KV
ESD according to IEC61000-4-2 contact discharge		± 30	KV
Junction temperature	T_J	125	$^{\circ}\text{C}$
Operating temperature	T_{OP}	-40~85	$^{\circ}\text{C}$
Storage temperature	T_{STG}	-55~150	$^{\circ}\text{C}$

Electrical Characteristics $\dot{A}T_a=25$ Unless otherwise specified $\dot{A}$

PARAMETER	Symbol	UNIT	Conditions	Min	Typ	Max
Reverse maximum working voltage	V_{RWM}	V				± 7
Reverse leakage current	I_R	nA	$V_{RWM} = 7$			100
Reverse breakdown voltage	V_{BR}	V	$I_{BR} = 1\text{mA}$	7.2		10.5
Reverse holding voltage	V_{HOLD}	V	$I_{HOLD} = 50\text{mA}$	7.2		10.5
Clamping voltage ¹⁾	V_{CL}	V	$I_{PP} = 16\text{A}$, $t_p = 100\text{ns}$		12.0	
Dynamic resistance ¹⁾	R_{DYN}				0.28	
Clamping voltage ²⁾	V_{CL}	V	$V_{ESD} = 8\text{kV}$		12.0	
Clamping voltage ³⁾	V_{CL}	V	$I_{PP} = 1\text{A}$, $t_p = 8/20 \text{ s}$		9	11
		V	$I_{PP} = 6\text{A}$, $t_p = 8/20 \text{ s}$		12	14
Junction capacitance	C_J	pF	$V_R = 0\text{V}$, $f = 1\text{MHz}$		10	13
		pF	$V_R = 2.5\text{V}$, $f = 1\text{MHz}$		8	11

(1). TLP parameter: $Z_0 = 50 \text{ } \Omega$, $t_p = 100\text{ns}$, $t_r = 2\text{ns}$, averaging window from 60ns to 80ns. R_{DYN} is calculated from 4A to 16A.

(2). Contact discharge mode, according to IEC61000-4-2.

(3). Non-repetitive current pulse, according to IEC61000-4-5.

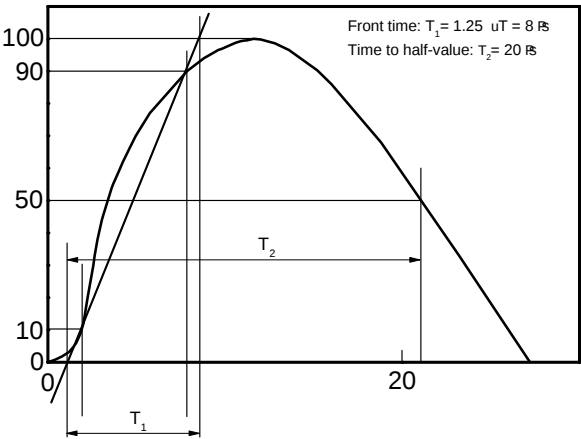
Ordering Information (Example)

PREFERRED P/N	UNIT WEIGHT(mg)	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
ESD7V0LB	Approximate 0.9	10000	100000	400000	Tape&reel

vCharacteristics (Typical)

820 μs waveform per IEC61000-4-5

Contact discharge current waveform per IEC61000-4-2



Clamping voltage vs. Peak pulse current

Capacitance vs. Reverse voltage

Non repetitive peak pulse power vs. Pulse time

Power derating vs. Ambient temperature

vRecommend land pattern (Unit:mm)

Notes:

This recommended land pattern is for reference purposes only.

Disclaimer

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